Dalton Transactions

Cite this: Dalton Trans., 2012, 41, 6299

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$Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$: new derivatives of the $Pr_3Rh_4Sn_{13}$ structure type

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Received 14th February 2012, Accepted 22nd March 2012 DOI: 10.1039/c2dt30339f

The new phases Ca₃Pt_{4+x}Ge_{13-y} (x = 0.1; y = 0.4; space group $I2_13$; a = 18.0578(1) Å; $R_I = 0.063$; $R_P = 0.083$) and Yb₃Pt₄Ge₁₃ (space group $P4_2cm$; a = 12.7479(1) Å; c = 9.0009(1) Å; $R_I = 0.061$, $R_P = 0.117$) are obtained by high-pressure, high-temperature synthesis and crystallize in new distortion variants of the Pr₃Rh₄Sn₁₃ type. Yb₃Pt₄Ge₁₃ features Yb in a temperature-independent non-magnetic 4f¹⁴ (Yb²⁺) configuration validated by X-ray absorption spectra and resonant inelastic X-ray scattering data. Ca₃Pt_{4+x}Ge_{13-y} is diamagnetic ($\chi_0 = -5.05 \times 10^{-6}$ emu mol⁻¹). The Sommerfeld coefficient $\gamma = 4.4$ mJ mol⁻¹ K⁻² for Ca₃Pt_{4+x}Ge_{13-y}, indicates metallic properties with a low density of states at the Fermi level in good agreement with electronic structure calculation ($N(E_F) = 3.3 \text{ eV}^{-1}/\text{f.u.}$)); the Debye temperature (θ_D) is 398 K.

Introduction

Intermetallic compounds with a crystal structure composed of rigid covalently bonded cage-forming frameworks enclosing electropositive metal atoms like rare-earth, actinide or alkalineearth show a wealth of topical physical phenomena such as valence fluctuations, Kondo behaviour, heavy-fermion properties, superconductivity, thermoelectricity, etc.¹⁻⁴ To this group of materials belong, in particular, intermetallic clathrates,^{5,6} compounds crystallizing in structures derived from the perovskite motif,⁷ filled skutterudites¹ and derivatives of the $Pr_3Rh_4Sn_{13}$ type.⁸ Recently, filled skutterudites with a new type of $[Pt_4Ge_{12}]$ framework MPt_4Ge_{12} (with M = Sr, Ba, La–Nd, Eu) were discovered.9,10 At ambient pressure the formation of filled skutterudites MPt₄Ge₁₂ has been observed only for light rare-earth (RE) metals, so that a high-pressure technique was used to synthesize representatives with heavier RE. Application of high-pressure has proven successful for syntheses of phosphorus-based skutterudites^{11,12} and SmPt₄Ge₁₂.¹³ However, in the samples with nominal composition $CaPt_4Ge_{12}$ and $REPt_4Ge_{12}$ (RE = Gd-Yb) three phases were observed: compounds with a stoichiometry $M_3Pt_4Ge_{13}$, MPtGe₂ and free Ge. Cubic symmetry and lattice parameter close to ~9.5 Å (deduced from the indexing of only

the strongest reflections) for the phases $M_3Pt_4Ge_{13}$ suggested resemblance with a $Pr_3Rh_4Sn_{13}$ type of structure.

This structure type is closely related to skutterudites and features the [Rh₄Sn₁₂] framework with cubooctahedral voids occupied by Pr cations as well as enlarged icosahedral cavities hosting the remaining Sn atoms (see discussion below). Intermetallic compounds with this atomic pattern were found in many systems A-T-X (where A = alkaline-earth, rare-earth or actinide metal, T = transition metal and X= In, Si, Ge or Pb).¹⁴

They became an object of numerous studies, mostly owing to the interesting interplay between magnetic and superconducting properties.^{15–19} Here, it should also be noted that the precise determination of the crystal structure of compounds of this type is difficult. One of the X atoms, residing in a position at the center of an enlarged regular icosahedral cavity, shows a local positional disorder or a formation of a random mixture of A and X or T and X elements. This is the case, e.g., in Ce₃Rh₄Sn₁₃²⁰ and Yb₃Co_{4.3}Sn_{12.7}.¹⁸ Some other members of this family crystallize with a doubled body-centered cubic unit cell in the noncentrosymmetric space group I4132 (i.e. La3Rh4Sn13²¹ and Gd₃Ir₄Sn₁₃²²). Moreover, in the single crystal X-ray diffraction data for the Pr₃Rh₄Sn₁₃ prototype, Miraglia et al.²³ observed superstructure reflections indicating a possible doubling of the unit cell. However, these authors could not completely refine the superstructure due to strong correlation of the refined parameters yielding undefined displacement ellipsoids. Finally, Tm₃Co₄Ge₁₃ adopts a commensurately modulated crystal structure.²⁴

In this paper, we report on the preparation, crystal structure and physical properties of two new phases, cubic $Ca_3Pt_{4+x}Ge_{13-y}$ and tetragonal Yb₃Pt₄Ge₁₃, both with crystal structures related to the Pr₃Rh₄Sn₁₃ type.

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Result and discussion

Structure determination

The powder synchrotron X-ray diffraction (XRD) pattern of $Ca_3Pt_{4+x}Ge_{13-y}$ (161 reflections) was successfully indexed on the basis of a body-centered cubic unit cell with a lattice parameter of a = 18.0578(1) Å. Analysis of the extinction conditions showed seven possible space groups with diffraction symbols: $m\bar{3}I$ ---, $m\bar{3}mI$ --- and mmI4--. As the first model for the refinement, the known structure of $La_3Rh_4Sn_{13}$ (space group $I4_132$, diffraction symbol $m\bar{3}mI4_1$ --, reflection conditions 00*l*, $l = 4n)^{21}$ was used. This refinement converged with reliability factors $R_{\rm I}$ = 0.086, $R_{\rm P} = 0.101$ and interatomic distances, which were in good agreement with the sum of atomic radii of the elements. However, the calculated intensity of some reflections was substantially lower than the experimentally observed one (inset Fig. 1). The differences cannot be explained by preferential orientation of the sample because the reflections do not belong to a distinct zone(s). This finding indicated that $Ca_3Pt_{4+x}Ge_{13-v}$ crystallizes most probably in one of the six space groups with diffraction symbols $m\bar{3}I$ --- or $m\bar{3}mI$ --- for which reflections 00l with l = 4n + 2 are also expected. However, the assignment of these reflections is ambiguous since in the cubic crystal system, a reflection like $(0\ 0\ 6)$ can also be indexed as (2 2 4).

Nevertheless, as one can see from Fig. 1, the intensity of the (2 4 4) peak is strongly reduced in the structural model with space group $I4_132$. The same situation holds for the reflection with index (8 8 14), alternative to (0 0 18) (not shown in Fig. 1). These were additional hints in favour of space groups with diffraction symbols $m\overline{3}I$ --- or $m\overline{3}mI$ ---. All attempts to find structural models for the new germanide in the centrosymmetric group $Im\overline{3}m$ as well as non-centrosymmetric groups I432 and

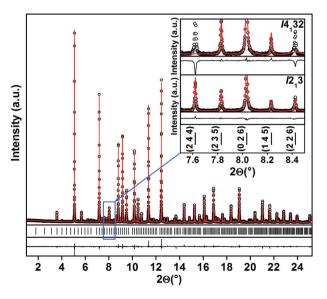


Fig. 1 Experimental (black circles) and calculated (red line) synchrotron XRD patterns ($\lambda = 0.39987$ (Å)) of Ca₃Pt_{4+x}Ge_{13-y}. The difference plot is shown as a black line in the bottom part. Reflection positions are indicated by ticks. Inset: calculated and measured intensities in space groups *I*4₁32 and *I*2₁3 for reflections in the 2 θ range of 7.5–8.5°.

Table 1 Crystallographic data for $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$ at 293 K

Composition	Ca ₃ Pt _{4+x} Ge _{13-y} (x = 0.1; y = 0.4)	Yb ₃ Pt ₄ Ge ₁₃
Space group Unit cell parameters	<i>I</i> 2 ₁ 3 (no. 199)	<i>P</i> 4 ₂ <i>cm</i> (no. 101)
a (Å) c (Å)	18.0578(1)	12.7479(1) 9.0009(1)
$V(Å^3)$	5888.3(1)	1462.7(1)
Formula units per cell, Z	16	4
Calc. density, $g \text{ cm}^{-3}$	8.256	10.185
Diffraction system	ID 31, ESRF	ID 31, ESRF
Radiation, λ (Å)	Synchrotron, 0.39987	Synchrotron, 0.39987
Step size (°2 θ)	0.001	
$R_{\rm I}/\dot{R}_{\rm P}^{\ a}$	0.063/0.083	0.061/0.117
${}^{a}R_{I} = \Sigma I_{i}^{obs} - I_{i}^{calc} / \Sigma I_{i}^{old} $ package WinCSD).	$ R_{\rm P} = \Sigma w (I_i^{\rm obs} - I_i^{\rm ca})$	$(L_i^{obs})^2 / \Sigma w (I_i^{obs})^2$. (Program

 $I\bar{4}3m$ failed. The structural model obtained in space group $Im\bar{3}$ (final values of reliability factors $R_{\rm I} = 0.096$, $R_{\rm P} = 0.098$) is characterized by strong disorder: four crystallographic positions are partially occupied by Ge atoms, whereas two other sites reveal random mixtures of Ge and Pt atoms. Some Ge–Ge distances are shortened by ~13%, Ca–Ge by ~10%, and the final refined composition Ca₃Pt_{4.2}Ge_{12.2} deviates strongly from the nominal one. To improve this situation, we attempted further symmetry reduction and successfully refined the structure in space group IZ_13 as evidenced by significantly lower residuals.

Details of the refinement of the crystal structure of $Ca_3Pt_{4+x}Ge_{13-y}$ (x = 0.1, y = 0.4) in space group I2₁3 are given in Table 1. Final values of atomic coordinates and displacement parameters together with the shortest interatomic distances are presented in Table 2. The refinement of this structural model provides good agreement between calculated and experimentally observed XRD intensities. In the initial refinement, strongly enhanced (by a factor of 3, compared to other Ge atoms) displacement parameters Biso for Ge1 and Ge4 indicated partial occupancy of these sites. On the other hand, the value of the displacement parameter of the atom occupying the 8a site was only 0.2(1) $Å^2$. Refinement with a random mixture of Ge and Pt atoms on this position and partial occupation of Ge1 and Ge4 sites leads to reliable values of the isotropic displacement parameters (Table 2). Based on the lowest observed reliability factors (Table 1) as well as reasonable interatomic distances (Table 2) we consider this structural model as the most suitable.

The strongest peaks in the powder XRD pattern of the Yb₃Pt₄Ge₁₃ sample, measured on a HUBER G670 imaging plate Guinier camera, were indexed using a cubic primitive lattice with $a_{cub} = 9.0045$ Å (some of them are shown in Fig. 2). The presence of additional weak reflections indicated a doubling of the unit cell. Indeed, all reflections observed in the XRD pattern were indexed with lattice parameter $a \approx 2a_{cub} = 18.0091$ Å of a body-centered cubic lattice. However, some peaks in this pattern are either broadened or show pronounced asymmetry (Fig. 2). This fact prompted us to perform a high resolution (HR) synchrotron XRD experiment. A clear splitting of the "broadened" and "asymmetrical" reflections is observed, thus indicating a

Table 2 Atomic coordinates, displacement parameters, and shortest interatomic distances (d_{\min}, A) in the crystal structures of $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$

Atom	Site	x	У	Ζ	$B_{\rm iso}({\rm \AA}^2)$	d_{\min} (Å)	CN
Cal	24 <i>c</i>	0.1263(7)	0.2524(9)	0.5009(8)	1.02(2)	-Ge1 - 2.92(1)	16
Ca2	24c	0.0018(8)	0.37190(9)	0.2512(7)	1.02(2)	-Ge8 - 3.01(2)	16
Pt1	8a	0.12241(2)	x	x	1.15(2)	-3Ge2 $- 2.474(6)$	9
Pt2	8 <i>a</i>	0.3754(2)	x	x	0.97(2)	-3Ge3 - 2.508(7)	9
Pt3	24c	0.1233(2)	0.3772(2)	0.3783(2)	0.73(1)	-1Ge6 $- 2.538(9)$	9
Pt4	24c	0.1243(2)	0.1251(2)	0.3763(2)	1.01(1)	-1Ge6 $- 2.475(9)$	9
Ge1 ^a	8 <i>a</i>	0.2481(2)	x	x	1.01(2)	-3Ge7 - 2.58(1)	12
Ge2	24c	0.0053(3)	0.3272(3)	0.5775(2)	1.66(2)	-1Pt1 $-2.474(6)$	10
Ge3	24 <i>c</i>	0.1056(3)	0.2471(4)	0.1813(2)	1.64(2)	-1Ge7 $-2.408(7)$	12
Ge4 ^b	24 <i>c</i>	0.0039(3)	0.1757(3)	0.4200(4)	0.92(2)	-1Pt4 $- 2.486(6)$	10
Ge5	24c	0.2478(3)	0.3112(3)	0.3812(4)	1.54(2)	-1Pt3 $- 2.545(7)$	13
Ge6	24c	0.0612(2)	0.4972(2)	0.1335(5)	1.64(2)	-1Pt4 $- 2.475(9)$	11
Ge7	24c	0.1213(3)	0.2508(3)	0.3136(4)	1.41(2)	-1Ge3 $- 2.408(7)$	13
Ge8	24c	0.0044(3)	0.3304(3)	0.0766(4)	1.49(2)	-1Pt4 $-2.486(7)$	11
Ge9	24c	0.1740(4)	0.4189(2)	0.2523(3)	1.55(2)	-1Pt3 $- 2.565(7)$	13
$T1^c$	8 <i>a</i>	0.0021(3)	x	x	1.37(2)	-3Ge6 - 2.632(6)	11
Yb ₃ Pt ₄ Ge ₁	3						
Yb1	2a	0	0	$0.0^{\ d}$	0.58(5)	-2Ge3 - 3.209(5)	16
Yb2	2b	1/2	1/2	0.0008(7)	0.72(5)	-4Ge7 $-2.971(7)$	16
Yb3	8e	0.1275(1)	0.3780(1)	0.2578(5)	0.75(2)	-1Ge8 $- 2.992(4)$	16
Pt1	8e	0.2504(1)	0.50110(2)	0.00591(6)	0.40(2)	-1Ge5 $- 2.519(4)$	9
Pt2	8e	0.0015(2)	0.2519(1)	0.0042(6)	0.44(1)	-1Ge9 $-2.487(8)$	9
Ge1	4d	0.1718(4)	x	0.1035(8)	0.4(1)	-2Pt2 - 2.560(6)	10
Ge2	4d	0.2471 (2)	x	0.7577(9)	0.63(3)	-1Ge5 $- 2.499(9)$	10
Ge3	4d	0.1727(4)	x	0.4131(7)	0.8(1)	-2Pt2 - 2.574(6)	12
Ge4	4d	0.3140(3)	x	0.0364(7)	1.1(1)	-2Pt1 - 2.535(4)	13
Ge5	4d	0.3108(3)	x	0.5111(1)	0.7(1)	-1Ge2 $- 2.499(9)$	13
Ge6	8e	0.1207(3)	0.6172(3)	0.3693(6)	0.91(5)	-1Pt1 $- 2.555(5)$	13
Ge7	8e	0.3443(2)	0.4987(2)	0.2553(8)	0.72(4)	-1Pt1 $- 2.544(8)$	13
Ge8	8e	0.0756(3)	0.5747(3)	0.0925(5)	0.68(5)	-1Pt1 $- 2.541(4)$	12
Ge9	8e	0.0422(2)	0.1763(2)	0.7512(8)	1.04(5)	-1Ge9 $-2.416(4)$	13

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tetragonal distortion of the lattice (Fig. 2). 122 peaks of the HR XRD pattern of Yb₃Pt₄Ge₁₃ were successfully indexed on the basis of a tetragonal primitive lattice with unit cell parameters a = 12.7479(1) Å, c = 9.0009(1) Å. The observed splitting pattern (*e.g.* (*h*00) reflections split into two with intensity ratio 2 : 1, Fig. 2) as well as the characteristic ratio of the tetragonal lattice parameters ($a_{tetr} \approx a_{cub} \sqrt{2}$, $c_{tetr} \approx a_{cub}$; Table 1) corroborates a close relationship of the atomic arrangement to the cubic prototype.

An analysis of the reflection conditions (l = 2n for (0kl); l =2n for (001)) in the HR XRD pattern of Yb₃Pt₄Ge₁₃ indicated 3 possible space groups: $P4_2/mcm$, $P4_2mc$ and $P\overline{4}2c$ (Fig. 3). The structural model in the space group $P4_2/mcm$ was obtained using direct methods. The final values of the reliability factors for the corresponding refinement were $R_{\rm I} = 0.077$, $R_{\rm P} = 0.141$. However, large displacement parameters for Ge atoms in the general position 16p ($B_{iso} = 4.13(2) \text{ Å}^2$) as well as some shortened (by 9%) Ge-Ge contacts suggested the non-centrosymmetric space group $P4_{2}mc$. Details of the refinement, final values of the atomic coordinates and displacement parameters together with the shortest interatomic distances are presented in Tables 1 and 2, respectively. The experimental and calculated powder XRD patterns for Yb₃Pt₄Ge₁₃ are shown in Fig. 3. In the refined structural model, atomic distances mostly agree well with the sum of atomic radii of the elements (Table 2). The refined displacement parameters indicate a fully ordered occupation of the position. All these facts, as well as the low final values of the R factors (Table 1) confirm the reliability of the obtained model.

Crystal chemistry

The crystal structures of Pr₃Rh₄Sn₁₃⁸ and filled skutterudite $(LaFe_4P_{12} type^{25})$ are commonly considered as derivatives of the cubic perovskite structure (space group $Pm\bar{3}m$, Fig. 4). The CaTiO₃ type (ABX_3^{26}) is usually presented as an array of cornersharing octahedra BX_6 . Cubooctahedral cavities in the free space between octahedra are filled by Ca atoms. One unit cell contains one cubooctahedron AX_{12} and one octahedron BX_6 (Fig. 4, left). Doubling of the unit cell parameters yields eight cubooctahedra and eight octahedra in the new cell. Tilting of the octahedra, in a way that two of the eight initial cubooctahedra are converted into icosahedra (colored yellow in Fig. 4) and distortion of the second type (red in Fig. 4, middle), leads to the formation of filled skutterudite type LaFe₄P₁₂ (space group $Im\bar{3}$). Three of the six distorted cubooctahedra may be considered as two bicapped trigonal prisms sharing a quadratic face (red in Fig. 4, middle). The remaining three can be represented by two tetragonal antiprisms with common quadratic face (blue in Fig. 4). The centers of these polyhedra are empty so that the transformations can be

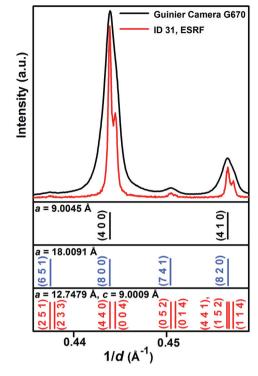


Fig. 2 Indexing of the powder XRD patterns of Yb₃Pt₄Ge₁₃ (black – laboratory data, HUBER G670 imaging plate Guinier camera (CuK_{\alpha1}); red – synchrotron data, ESRF ID31, $\lambda = 0.39987$ Å) with cubic primitive ($a_{cub} = 9.0045$ Å), cubic body-centered ($a_{doubled} \approx 2a_{cub} = 18.0091$ Å) and tetragonal lattices ($a_{tetr} \approx a_{cub} \sqrt{2}$ and $c_{tetr} \approx a_{cub}$). In the high-resolution XRD pattern clear splitting of the reflections is observed.

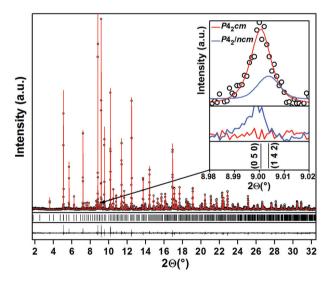


Fig. 3 Experimental (black points) and calculated (red line) XRD synchrotron patterns ($\lambda = 0.39987$ (Å)) of Yb₃Pt₄Ge₁₃. Peak positions are given by black ticks; the difference plot is shown as a black line in the bottom part. Inset: 2θ range of 8.98–9.02° for the models in the space groups $P4_2cm$ and $P4_2/ncm$. Reflection (0 5 0), which breaks the reflection condition h + k = 2n for (*hk*0), confirms the true choice of the noncentrosymmetric space group.

balanced as follows:

$$8ABX_3 \xrightarrow{\text{def.}} A_8B_8X_{24} \xrightarrow{-6A} A_2B_8X_{24} \longrightarrow 2AB_4X_{12}$$

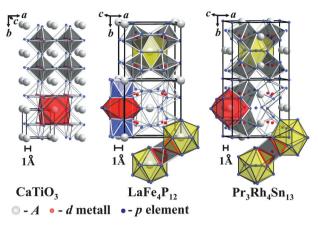


Fig. 4 Relationship between the crystal structures of $CaTiO_3$, $Pr_3Rh_4Sn_{13}$ and $LaFe_4P_{12}$ types (see text).

Rotation of the icosahedron located at the body center of the cell in the LaFe₄P₁₂ type by 90° around an axis parallel to a cube edge leads to a transformation of the octahedron around the *B* atom into a trigonal prism (gray in Fig. 4, right). This geometrical rearrangement is indicated in Fig. 4 right, where respective triangular faces of the trigonal prism and octahedron (trigonal antiprism) are marked by thick red lines. The appearance of an array of corner-sharing trigonal prisms in the new structure is accompanied by a change of the symmetry to $Pm\bar{3}n$.²⁷ Less distorted cubooctahedra (red in Fig. 4, right), as compared to the LaFe₄P₁₂ type, are filled by Pr (similar as in the perovskite structure). The icosahedra are filled by additional *X* atoms (yellow in Fig. 4, right), as this was already found in the skutterudite $Sn_xPt_4Sn_ySb_{12-y}$.⁸ The so-formed structure is known as the $Pr_3Rh_4Sn_{13}$ type.⁸ The composition transformation may be described by the following equation:

$$2AB_4X_{12} \rightarrow A_2B_8X_{24} \stackrel{+6A-2A+2X}{\rightarrow} A_6B_8X_{26} \rightarrow 2A_3B_4X_{13}$$

Both structures, $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Rh_4Sn_{13}$, as well as $La_3Rh_4Sn_{13}^{21}$ show the same structural motif as in the $Pr_3Rh_4Sn_{13}$ prototype (Fig. 5). The only difference is, that in $Pr_3Rh_4Sn_{13}$ icosahaedra and trigonal prisms are regular while in all three derivative structures they are distorted. However, it should be noted that interatomic distances are very different in all these compounds, especially in the *X*-atom networks.

Most interatomic distances in the structure of $Pr_3Rh_4Sn_{13}^{8,23}$ are slightly larger than the sums of atomic radii of elements $(r_{Pr} = 1.83 \text{ Å}, r_{Rh} = 1.34 \text{ Å}, r_{Sn} = 1.41 \text{ Å}).^{29}$ Only the Rh–Sn contacts are shortened by ~3%. If one assumes bonding limits within the sum of atomic radii (d_{\min}) multiplied by $\sqrt{2}$,³⁰ then the coordination number (CN) for the Pr atom in this structure is 16 and the coordination polyhedron (CP) is a distorted cubooctahedron with 4 additional vertices. For the Rh atoms we have CN = 9 (three-capped trigonal prism), for Sn1 CN = 12 (regular icosahedron), and for Sn2 CN = 14 (14-vertices polyhedron). In the planar nets occurring at y = 1/2 the Sn-atoms form chains of condensed triangles and rectangles (Fig. 5, left panel). In the structure of La₃Rh₄Sn₁₃²¹ the Rh–Sn contacts are shortened already by ~4%, however, other distances are still larger than the sums of atomic radii of elements ($r_{La} = 1.88 \text{ Å}$).²⁹ Some Sn–Sn

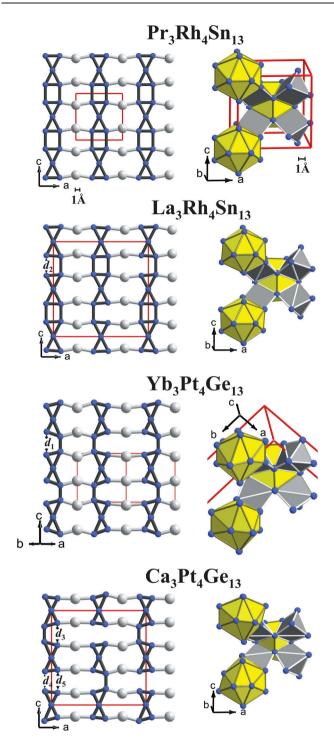


Fig. 5 Pr₃Rh₄Sn₁₃ prototype and related structures: (left panel) planar nets occurring at y = 1/2 with interatomic contacts which do not exceed the distance limit $d_{\min} \sqrt{2}$, 2.978(1) Å $\leq d \leq 3.738(2)$ Å for Pr₃Rh₄Sn₁₃; 2.499(9) Å $\leq d \leq 3.40(1)$ Å, $d_1 = 4.273(9)$ Å for Yb₃Pt₄Ge₁₃; 2.98(2) Å $\leq d \leq 3.77(1)$ Å, $d_2 = 4.16(1)$ Å for La₃Rh₄Sn₁₃ and 2.407(7) Å $\leq d \leq 3.36(1)$ Å, $d_3 = 4.291(8)$ Å, $d_4 = 3.82(1)$ Å, $d_5 = 4.38(1)$ Å for Ca₃Pt_{4+x}Ge_{13-y}; (right panel) regular icosahedra (Pr₃Rh₄Sn₁₃) or distorted icosahedra (La₃Rh₄Sn₁₃, Ca₃Pt_{4+x}Ge_{13-y} and Yb₃Pt₄Ge₁₃) interlinked by corner-sharing distorted trigonal prisms.

contacts exceed the $d_{\min} \sqrt{2}$ limit, leading to the distortions in the nets analogous to those observed in Pr₃Rh₄Sn₁₃ (Fig. 5, left panel).

The situation concerning the interatomic distances changes significantly when going to the germanides $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$ ($r_{Ca} = 1.97$ Å, $r_{Yb} = 1.94$ Å, $r_{Pt} = 1.38$ Å, $r_{Ge} = 1.23$ Å).²⁹ *A*-Pt contacts become shorter by 6% and 4.2% respectively (Table 2); *A*-Ge distances shrink by 6% and even by 8.7% in the case of $Ca_3Pt_{4+x}Ge_{13-y}$. Similar as the Rh-Sn contacts in the $Pr_3Rh_4Sn_{13}$ and $La_3Rh_4Sn_{13}$ stannides, the Pt-Ge distances in the structures of $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$ germanides are shortened by 5.2% and 4.7%. Ge-Ge contacts are close to the sum of atomic radii (shortening by only ~2% in both compounds, Table 2). A characteristic feature of all the compounds is the absence of short *T*-*T* contacts.

The shortening of A-Pt and A-Ge distances in the structures of Ca₃Pt_{4+x}Ge_{13-y} and Yb₃Pt₄Ge₁₃ is also accompanied by the increase of some Ge–Ge distances, which leads to the reduction of the CN of Ge atoms. In the crystal structure of the Pr₃Rh₄Sn₁₃ prototype Sn atoms adopt CN = 12 (icosahedron) and 14 (14vertices polyhedron). In the new germanides, the CN for Ge atoms vary between 10 and 13 (Fig. 5, left panel). In the net at y = 1/2, analogous to those in the structure of Pr₃Rh₄Sn₁₃ type, more Ge–Ge contacts are broken (Fig. 5, left panel).

The atoms A = Ca, La, Yb and T = Rh, Pt in the stannide and germanide derivatives remain almost in the same positions as in the prototype, while distortions in the X = Ge, Sn sublattices lead to the loss of the center of symmetry (for La₃Rh₄Sn₁₃ and Ca₃Pt_{4+x}Ge_{13-y}) or even to a further reduction of symmetry, as observed for Yb₃Pt₄Ge₁₃.

Such close and subtle relationship between these 4 structure types explains the close resemblance of the observed XRD powder patterns on a low level of resolution.

Electronic structures

The crystal structures of Ca₃Pt_{4+x}Ge_{13-y} and Yb₃Pt₄Ge₁₃ are rather complex. To facilitate a qualitative interpretation of the electronic structures, we first present the results for the ideal cubic Ca₃Pt₄Ge₁₃ in the undistorted structure of the Pr₃Rh₄Sn₁₃ type, where the lattice parameter is set to a = 9.0289 Å and atomic positions relaxed to find the equilibrium structure. The resulting electronic density of states (DOS) (Fig. 6) features Ge 4s and Pt 6s states lying between -13 and -7 eV. The broad valence band above -6 eV is formed by Ge 4p states, with a large contribution of Pt 5d states below E_F and Ca 4s states above the Fermi level. The electronic DOS for the idealized cubic structure of Ca₃Pt₄Ge₁₃ suggests a predominantly ionic bonding between Ca²⁺ and the Pt–Ge anionic framework.

Pt retains the 5d shell nearly filled (8.75 out of 10 electrons below the Fermi level). This shifts Pt states to lower energies. The Pt d-states are split into two groups: one at -6 eV < E < -4eV reflects more localized states; the other—below -8 eV and above -4 eV—represents electrons participating in the bonding with Ge. This indicates covalent Pt–Ge interactions, which are well in agreement with the close electronegativities of both elements. The itinerant states at the Fermi level mostly originate from Ge 4p. The idealized crystal structure features two Ge positions, with Ge1 forming the Pt–Ge framework and Ge2 occupying the icosahedral voids. Both types of Ge atoms produce similar contributions to the bands at the Fermi level which is



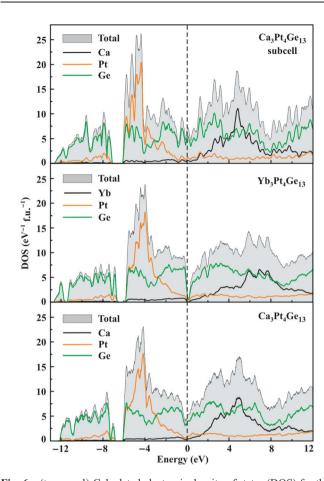


Fig. 6 (top panel) Calculated electronic density of states (DOS) for the idealized cubic structure (subcell) of $Ca_3Pt_4Ge_{13}$ (top panel), experimental crystal structures of $Yb_3Pt_4Ge_{13}$ (middle panel) and $Ca_3Pt_{4+x}Ge_{13-y}$ (bottom panel). The Fermi level is indicated by the dashed line. The 4f orbitals of Yb were considered as core states and, therefore, are not present in the figure. For the Ca compound, the stoichiometric composition and the fully ordered crystal structure were assumed (see text).

located on a spike of the DOS, suggesting the instability of the idealized cubic structure.

The electronic structures of $Yb_3Pt_4Ge_{13}$ and stoichiometric $Ca_3Pt_4Ge_{13}$ in the experimentally observed supercells show both the ionic state of Ca^{2+} and Yb^{2+} , the large filling of the Pt 5d shell, and the predominantly Ge 4p states at the Fermi level (Fig. 7). However, the Fermi level is now located in a dip of the DOS, which is especially well pronounced in the Yb compound.

Since the dip around 0 eV is missing in the idealized cubic structure of $Ca_3Pt_4Ge_{13}$ (Fig. 6), the emergence of this dip is attributed to the slight structural reorganization and the formation of superstructures. A closer inspection of the idealized cubic structure and real crystal structures established in this work reveals a change in the arrangement of Ge atoms. The idealized structure features Ge1 atoms forming the Pt–Ge framework and Ge2 atoms located in the voids. The Ge1–Ge2 distances exceed 3 Å and indicate a rather weak bonding for the Ge2 site. The superstructures reveal shortened Ge1–Ge2 distances that evidence the formation of covalent bonds and the involvement of all Ge atoms into the anionic framework. The formation of additional Ge–Ge bonds naturally leads to the separation of Ge

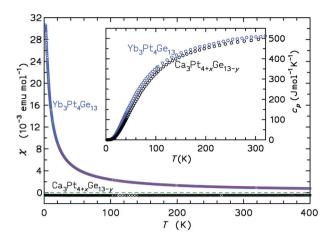


Fig. 7 Molar magnetic susceptibilities, $\chi(T)$, of Ca₃Pt_{4+x}Ge_{13-y} (black circles) and Yb₃Pt₄Ge₁₃ (blue circles). The modified Curie–Weiss fit (see text) for the Yb compound is indicated by a red line. Zero susceptibility is indicated by dashed green line, as guide for eyes only. The inset shows the molar heat capacities. In the case of Ca₃Pt_{4+x}Ge_{13-y} both molar properties were calculated for x = 0 and y = 0, *i.e.* for the idealized composition Ca₃Pt₄Ge₁₃.

4p states into the bonding and antibonding bands, and to the ensuing reduction of the DOS at the Fermi level. Particularly, we found $N(E_{\rm F}) = 2.2 \ {\rm eV}^{-1}/{\rm f.u.}$ and 3.3 ${\rm eV}^{-1}/{\rm f.u.}$ in Yb₃Pt₄Ge₁₃ and stoichiometric Ca₃Pt₄Ge₁₃, respectively. Replacing Ge2 by Pt in the Ca compound will likely lead to a further reduction in the DOS at Fermi level, thus supporting the stabilization of the crystal structure.

Physical properties

The magnetic susceptibilities, $\chi(T)$, of the Ca₃Pt_{4+x}Ge_{13-v} and Yb₃Pt₄Ge₁₃ species, for the latter together with a fit to a modified Curie–Weiss law in the temperature range 20–400 K, are shown in Fig. 7. The obtained fitting parameters are $\chi_0 =$ $+2.0 \times 10^{-4}$ emu mol⁻¹, C = 0.230 emu mol⁻¹ K and $\theta_{\rm P}$ = -6.0 K, suggesting antiferromagnetic interactions. For the Yb₃Pt₄Ge₁₃ sample a cusp at $T_N = 2.3$ K in $\chi(T)$ is observed in low fields ($\mu_0 H \leq 0.1$ T). It is attributed to antiferromagnetic ordering of the Yb³⁺ moments in the impurity phase Yb₂O₃.³¹ Assigning the whole paramagnetic moment of the Yb₃Pt₄Ge₁₃ sample to the Yb₂O₃ impurity, the effective magnetic moment $\mu_{\rm eff}$ of 1.36 $\mu_{\rm B}$ per formula unit (derived from C) corresponds to 9.0% Yb^{3+} species and thus 0.8 wt% of Yb_2O_3 in the sample. This finding is in fair agreement with the results from XAS, RIXS and EDXS studies reported below. No signature of Yb₂O₃ is observed in the XRD data, since 0.8 wt% is below the estimation limit of the method.

The susceptibility of Ca₃Pt_{4+x}Ge_{13-y} is negative with a weak positive linear temperature dependence caused by minor paramagnetic impurities (assuming magnetic species or charged point defects with a S = 1/2 moment the concentration is 0.10 mol%). The extrapolated χ_0 at T = 0 K is -505×10^{-6} emu mol⁻¹. No superconductivity or other phase transitions were observed for both compounds down to 1.8 K in fields $\mu_0 H \ge 2$ mT.

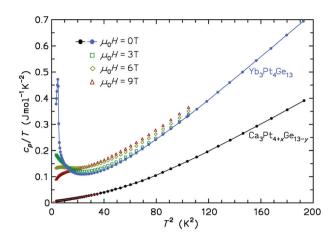


Fig. 8 Low-temperature specific heat $c_p(T,H)$ for Ca₃Pt_{4+x}Ge_{13-y} (black circles with line) and Yb₃Pt₄Ge₁₃ (blue circles with line as guide for eye only) in zero field. For the Yb compound also data for different magnetic fields are shown. The fit (see text) to the Ca₃Pt_{4+x}Ge_{13-y} data for $T^2 < 36$ K² is indicated by a red line.

The molar heat capacities $c_n(T)$ of both samples are given in the inset of Fig. 7. The values of 492 J mol $^{-1}$ K $^{-1}$ and 507 J mol⁻¹ K⁻¹ observed at 298 K for the Ca and Yb compound agree well with the Dulong–Petit law ($c_P \approx 3nR$, where n is the number of atoms per f.u.). Generally, the specific heat of Yb₃Pt₄Ge₁₃ is slightly larger than for Ca₃Pt_{4+x}Ge_{13-y} since the heavier Yb atoms (compared to Ca) lead to a lower Debye temperature. The low-temperature specific heats are given in Fig. 8 in a c_p/T vs. T^2 representation. The Ca compound data for $T \le 6$ K can be described by $c_p(T) = \gamma T + \beta T^3 + \delta T^5$, where γ is the Sommerfeld coefficient of the electronic heat capacity, and β and δ are the first terms of the harmonic lattice approximation for the phonon contribution. The positive deviation of $c_p(T)$ at higher temperatures is due to Einstein-like phonon modes which arise from vibration of the weakly bonded Ca atoms in their large atomic cages. No sensible model including these Einstein modes in order to describe $c_p(T)$ at higher temperatures, as for $MFe_4Sb_{12}^{32}$ or $MPt_4Ge_{12}^{9}$ filled skutterudite compounds, could be found for $Ca_3Pt_{4+x}Ge_{13-y}$ A fit with the simple relation above (see red line in Fig. 9), in a temperature range of 1.8-6 K results in $\gamma = 4.4$ mJ mol⁻¹ K⁻², $\beta = 6.2 \times 10^{-4}$ J mol⁻¹ K⁻⁴ corresponding to an initial Debye temperature $\theta_D(0) = 398$ K, and $\delta =$ $6.6 \times 10^{-6} \text{ J mol}^{-1} \text{ K}^{-6}$. The small value of γ indicates a low DOS at the Fermi level of ≈ 1.9 states eV⁻¹ f.u.⁻¹ and metallic properties of $Ca_3Pt_{4+x}Ge_{13-y}$

The specific heat of the Yb₃Pt₄Ge₁₃ sample below 6 K is dominated by the antiferromagnetic ordering transition of the Yb₂O₃ impurity, which is smeared out to higher temperatures with increasing external magnetic field (see Fig. 8). The tentative fit to the equation given above leads to the values of the Debye temperature ($\theta_D(0) \sim 310$ K, lower than for Ca₃Pt_{4+x}Ge_{13-y}) and the electronic coefficient γ (<50 mJ mol⁻¹ K⁻²). However, these values are estimated with relatively low precision, because we have to account for the Yb₂O₃ contribution using an additional a/T^2 term that approximates the high temperature limit of the magnetic specific heat. Nevertheless, our tentative estimate consistently shows the low coefficient γ ; which would not support

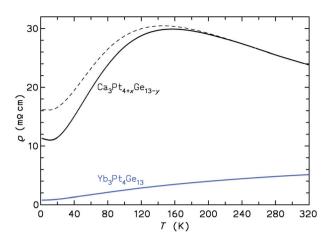


Fig. 9 Electrical resistivity $\rho(T)$ of polycrystalline Yb₃Pt₄Ge₁₃ (full blue line) and of polycrystalline Ca₃Pt_{4+x}Ge_{13-y} in zero magnetic field (full black line) and in a field $\mu_0 H = 9$ T (dashed black line).

an intermediate valence state, thus confirming the divalent state of Yb species in $Yb_3Pt_4Ge_{13}$.

The electrical resistivities, $\rho(T)$, of the polycrystalline pieces of both compounds are displayed in Fig. 9. The residual resistance ratio of 6.3 indicates a reasonably good crystalline quality with respect to disorder and defects. Albeit having a temperature dependence typical for a metal, both the residual ($\rho_0 = 0.8 \text{ m}\Omega$ cm) as well as the room-temperature resistivity ($\rho(300 \text{ K}) =$ 5.0 m Ω cm) of Yb₃Pt₄Ge₁₃ are very high and well above the Ioffe–Regel limit (~0.1 m Ω cm). The magnetoresistance increase is largest for the minimum temperature (1.8 K) and amounts to +9.3%.

The $Ca_3Pt_{4+x}Ge_{13-v}$ sample shows even higher resistivity: the residual resistivity is $\rho_0 = 11.3 \text{ m}\Omega$ cm, then, with increasing temperature, $\rho(T)$ goes through a shallow minimum of ρ_{\min} = 11.0 m Ω cm at 11.0 K, then shows an increase and a maximum of $\rho_{\rm min}$ = 30.0 m Ω cm at 157 K, and finally decreases again $(\rho(300 \text{ K}) = 23.8 \text{ m}\Omega \text{ cm})$. Such values and temperature characteristics can be found in doped (impure) semiconductors. This finding suggests that the off-stoichiometric composition of $Ca_3Pt_{4+x}Ge_{13-y}$ leads to the impurities that capture charge carriers, or triggers the formation of a small band gap. This would be in agreement with a much smaller DOS at $E_{\rm F}$ derived from the electronic specific heat coefficient γ (1.9 eV⁻¹ f.u.⁻¹) rather than from the electronic structure calculation (3.3 eV^{-1} f.u.⁻¹). The magnetoresistance increase for $Ca_3Pt_{4+x}Ge_{13-y}$ is the largest at $T \approx 13$ K and amounts to 47%, in agreement with a very low concentration of mobile charge carriers. The magnetoresistance decreases gradually with increasing temperature and vanishes above the temperature of the resistivity maximum.

Spectroscopic study of Yb₃Pt₄Ge₁₃. X-Ray absorption spectra measured at the Yb L_{III} edge (Fig. 10) at T = 5 K and 293 K are coincident. They show one dominant maximum reflecting the contribution of Yb with 4f¹⁴ configuration (Yb²⁺). Additionally, both spectra reveal a shoulder on the higher energy side that indicates contributions of the 4f¹³ (Yb³⁺) state. This can be explained by the presence of the Yb₂O₃ impurity in the sample, as further evidenced by $\chi(T)$, $c_p(T)$ and WDXS studies.

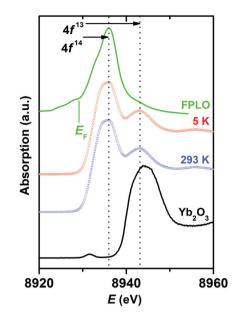


Fig. 10 Experimentally obtained high energy resolution XANES (HERFD) at the Yb L_{III} edge of Yb₃Pt₄Ge₁₃ and Yb₂O₃ together with the theoretically (FPLO) calculated Yb 5d DOS of Yb₃Pt₄Ge₁₃.

The contribution of Yb 5d electrons to the DOS, obtained from the *ab initio* electronic structure calculations using the FPLO code, is shown in Fig. 10. The indicated Fermi level E_F separates the occupied and unoccupied states. The calculated DOS curve was shifted to coincide with the maximum of the main edge absorption transition of Yb₃Pt₄Ge₁₃. It describes well the first absorption maximum and confirms also a negligible contribution of Yb²⁺ with 4f¹⁴ configuration to the maximum at higher energy, which is a clear indication of the presence of Yb³⁺ species with 4f¹³ configuration (Yb₂O₃) in the measured XANES spectra of the Yb₃Pt₄Ge₁₃ sample.

Fig. 11 shows the experimental (left) and theoretical (right) core-to-valence resonant inelastic X-ray scattering (RIXS)³³ profiles of the Yb₃Pt₄Ge₁₃ and Yb₂O₃ compounds. The RIXS data are shown here as a contour map in a plane of incident and transferred photon energies, where the vertical axis represents the energy difference between the incident and emitted energies. The experimental data were obtained with excitation energies near the maximum of the main Yb $L_{\rm III}$ absorption edge. Two types of excitations are observed: elastic scattering at ~0 eV and inelastic scattering features at higher energy transfer. Core-to-valence RIXS calculations at the Yb $L_{\rm III}$ edge were performed by inserting the Yb 5d pDOS into the Kramers–Heisenberg equation:³⁴

$$F(\Omega,\omega) = \int_{\varepsilon} \mathrm{d}\varepsilon \frac{\rho(\varepsilon)\rho'(\varepsilon + \Omega - \omega)}{(\varepsilon - \omega)^2 + (\Gamma_n^2/4)} \tag{1}$$

where ρ and ρ' are densities of the occupied and unoccupied Yb 5d states, respectively, while Ω and ω represent the energies of the incident and scattered photons, respectively; Γ_n is the lifetime broadening of the Yb $2p_{3/2}$ state, which is of 4.6 eV.³⁵ The validity of this approximation³⁴ can be evaluated by comparison of experimental and theoretical results.³³ An elastic peak due to

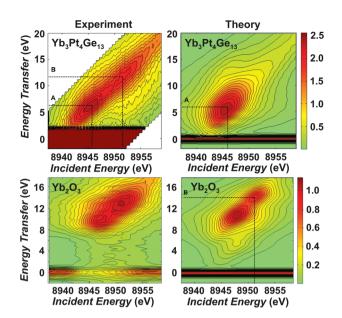


Fig. 11 Full experimental (left) and theoretical (right) core-to-valence RIXS intensities displayed as contour maps with axes corresponding to incident and transferred energies over the Yb $L_{\rm III}$ absorption edge of the Yb₃Pt₄Ge₁₃ (top) and Yb₂O₃ (bottom) compounds. Variations of the colors in the plot relate to the different scattering intensities.

Thomson scattering was added to the RIXS planes to facilitate comparison with experiment.

The idea to relate the RIXS spectral features to the DOS was initially introduced by Jimenez-Mier *et al.*³⁴ The RIXS process at the Yb $L_{\rm III}$ edge is identified as the convolution of the occupied and unoccupied Yb 5*d* DOS. Here we used the projected DOS obtained in full multiple scattering FEFF 9.0³⁶ calculations. The input files are based on the crystal structure of Yb₃Pt₄Ge₁₃ (Tables 1 and 2) and the crystal structure of Yb₂O₃ reported in the literature.³¹ Calculations are made for all the Yb atoms in a cluster of ~60 atoms (6.0 Å radius) for both structures. Full multiple scattering (FMS) calculations are performed using a Hedin-Lundqvist self-energy correction and other standard cards. More details about the FEFF code are reported elsewhere.³⁶

Experimental RIXS data for $Yb_3Pt_4Ge_{13}$ (Fig. 11) demonstrate the splitting of the RIXS features in the valence band at ~6 and ~12 eV in energy transfer (marked A and B) which arise from the two contributions of Yb^{2+} and Yb^{3+} , respectively, to the XANES spectrum. Feature A can be reproduced by theoretical calculations reported in Fig. 6 with respect to feature shape, position and relative intensities. However, feature B cannot be simulated by this model.

Nevertheless, we find a reasonably good agreement between theoretical calculations and experimental RIXS data for Yb_2O_3 (Fig. 11). A detailed examination of the RIXS data for Yb_2O_3 reveals that the shape and position of the feature B in the RIXS plane of $Yb_3Pt_4Ge_{13}$ is similar to the one reported in the RIXS plane for Yb_2O_3 (marked feature B in Fig. 11). This is an additional indication that feature B in the RIXS plane of $Yb_3Pt_4Ge_{13}$ arises from the impurity Yb_2O_3 in the $Yb_3Pt_4Ge_{13}$ sample.

Conclusions

Applying high-pressure synthesis, new ternary germanides $Ca_3Pt_{4+x}Ge_{13-y}$ with cubic structure (p = 8(1) GPa; T = 850 (100) °C for 2 h) and tetragonal Yb₃Pt₄Ge₁₃ (p = 2(1) GPa; T = 800(100) °C for 2 hours) were synthesized. Their crystal structures are closely related to the Pr₃Rh₄Sn₁₃ type. Distortions in the Ge sublattice reduce the symmetry of the new structures. X-Ray absorption spectroscopy, resonant inelastic X-ray scattering, magnetic susceptibility and specific heat measurements suggest that the Yb atoms in Yb₃Pt₄Ge₁₃ adopt a temperature-independent 4f¹⁴ (Yb²⁺) configuration. Ca₃Pt_{4+x}Ge_{13-y} is diamagnetic with a very low concentration of mobile charge carriers, which is in agreement with a low density of states at the Fermi level (1.9 eV⁻¹ f.u.⁻¹).

Experimental

Synthesis

The precursor samples with the molar ratios {Ca,Yb} : Pt : Ge of 3:4:13 were prepared by arc melting of the metals Ca (Alfa Aesar, 99.987 wt%), Yb (Ames, 99.9 wt.%), Pt (ChemPur, 99.9 wt%) and semiconductor-grade Ge (ChemPur, 99.9999 wt%). The resulting ingots were placed in glassy-carbon crucibles, sealed in tantalum tubes, which were then encapsulated in the evacuated quartz ampoules. After annealing at 700 °C for 7 days the tubes were quenched in water. Sample handling including the prearrangement of the high-pressure setup was performed in argon-filled glove boxes (MBraun, $p(H_2O) < 1 \text{ ppm}; p(O_2) < 1 \text{ ppm}$).

High-pressure and high-temperature preparation experiments have been performed in a multi-anvil press. Force redistribution is realized by a Walker module and MgO octahedra with an edge length of 18 mm.³⁷ Elevated temperatures are realized by resistive graphite heaters. The pressure and temperature calibration is performed in separate calibration experiments by in situ monitoring of the resistance changes in bismuth^{38,39} and by heating runs with a thermocouple, respectively. Hexagonal boron nitride proved suitable as a crucible material. In order to avoid contamination with oxygen, the high-pressure assembly was transferred to the press directly before synthesis. After the experiment, the setup was immediately removed from the Walker module and transferred back into a glove box, where the sample was recovered from the crucible. However, despite all precautions a small amount of Yb₂O₃ (<0.8 wt%) was detected in the studied samples by physical properties and WDXS studies.

To optimize the syntheses, samples with stoichiometric 3:4:13 compositions were pressed at 2, 4, 6 and 8 GPa and temperatures of 800(100) °C, 850(100) °C and 900(100) °C. In the case of $Ca_3Pt_{4+x}Ge_{13-y}$ the single phase sample was obtained at 8(1) GPa and a temperature of 850(100) °C. In the samples synthesized under other conditions besides the cubic compound CaPtGe₂, PtGe₂ and Ge were observed always as additional phases. Yb₃Pt₄Ge₁₃ was synthesized at 2(1) GPa and 800 (100) °C. At higher pressures and temperatures tetragonal Yb₃Pt₄Ge₁₃ decomposes partially, so that also free Ge as well as PtGe₂ are observed in the XRD powder patterns.

The synthesized products could be separated easily from the crucibles, thus no notable reaction with BN was observed. This was confirmed by powder XRD and energy dispersive X-ray analysis. For the high-pressure syntheses, typical annealing times were 2 h. Samples were allowed to cool down to room temperature before decompression. The resulting samples are dense and stable in air.

X-Ray diffraction. All samples were characterized by powder XRD performed on a HUBER G670 imaging plate Guinier camera equipped with a Ge monochromator (CuK_{α 1} radiation, $\lambda = 1.54056$ Å). Phase analysis and indexing of diffraction patterns were performed using the WinXPOW program package (STOE WinXPOW, Version 2, STOE and Cie GmbH, Darmstadt). All peaks in the powder diffraction patterns of $Ca_3Pt_{4+x}Ge_{13-y}$ and $Yb_3Pt_4Ge_{13}$ compounds could be indexed assuming cubic symmetry and lattice parameter $a \approx 18$ Å. However in the case of Yb₃Pt₄Ge₁₃ some reflections were broadened (Fig. 1), which is an indication of a possible symmetry reduction. Therefore, we collected high-resolution powder XRD data with a wavelength of 0.39987 Å at the ID31 beamline of the European Synchrotron Radiation Facility (ESRF). The signal was measured on powder samples contained in thin-walled quartz-glass capillaries with an external diameter of 0.5 mm. Eight scintillation detectors, each preceded by a Si(111) analyzer crystal, in the angle range $2\theta = 1-30^\circ$ were used. To achieve good statistics and to avoid the effects of preferred orientation, the capillary was spun during the experiment. Indexing of diffraction patterns, determination of crystal structures as well as full-profile Rietveld refinement were performed using the program package WinCSD.40

Metallography

Polished cuts of the Ca₃Pt₄Ge₁₃ and Yb₃Pt₄Ge₁₃ samples were examined optically (Zeiss Axioplan 2) and by energy-dispersive X-ray spectroscopy (EDXS) on a scanning electron microscope Philips XL30 SEM. The average compositions were Ca_{3.2(2)}Pt_{3.9(2)}-Ge_{12.9(2)} and Yb_{3.1(2)}Pt_{4.1(2)}Ge_{12.8(2)}, which agrees well with the nominal one and that deduced from the crystal structure refinements.

Estimation of the oxygen content in the $Yb_3Pt_4Ge_{13}$ sample was performed by EDXS and wave length dispersive X-ray analysis (WDXS) using a Jeol JSM 6610 scanning electron microscope equipped with an UltraDry EDS detector and MagnaRay WDS spectrometer (ThermoFisher NSS7 system).

The element mapping based on the *K*- and *L*-lines X-ray intensities shows well defined Yb₂O₃ particles and further minority phase PtGe₂ (see Fig. 12). The OK_{α} mapping with the WSi₆₀ monochromator crystal reveals no significant intensity at the majority phase Yb₃Pt₄Ge₁₃.

Electronic structure calculations. Scalar-relativistic electronic structures of $Ca_3Pt_4Ge_{13}$ and $Yb_3Pt_4Ge_{13}$ were calculated in the framework of density-functional theory (DFT) using the full-potential FPLO code (version 9.01–35) with the basis set of local orbitals.⁴¹ The exchange-correlation potential by Perdew and Wang was applied.⁴² The *k*-meshes included 120 points for $Yb_3Pt_4Ge_{13}$ (80 atoms in the unit cell) and 32 points for

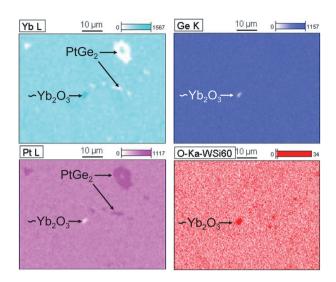


Fig. 12 X-Ray intensity element mappings show the EDXS absolute counts of YbL, PtL and GeK lines. The WDXS intensity of $OK\alpha$ line was measured with the WSi₆₀ spectrometer. The Yb₃Pt₄Ge₁₃ sample contains small grains of the minority phases PtGe₂ and Yb₂O₃ (labelled in figure).

Ca₃Pt₄Ge₁₃ (160 atoms in the unit cell) in the symmetry-irreducible part of the first Brillouin zone. The calculation was done for the experimentally obtained model of $Yb_3Pt_4Ge_{13}$ and for the fully ordered model Ca₃Pt₄Ge₁₃, with experimental lattice parameter and the Ge1 and Ge4 positions fully occupied, as well the *T*1 position occupied solely by Ge. In addition, the calculations were made for Ca₃Pt₄Ge₁₃ with a crystal structure of the Pr₃Rh₄Sn₁₃ type.

Physical properties. The magnetization of polycrystalline sample pieces was measured in a SQUID magnetometer (MPMS XL-7, Quantum Design) in external fields $\mu_0 H$ between 2 mT and 7 T and temperatures between 1.8–400 K. The heat capacity measurements were performed with a relaxation-type calorimeter (PPMS, Quantum Design) in magnetic fields up to 9 T between 1.8 and 320 K. Electrical resistivity was determined with a low-frequency ac technique on a PPMS platform in zero and 9 T fields.

X-Ray absorption spectroscopy (XAS) and resonant inelastic X-ray scattering (RIXS). The experiments were performed at beamline ID26 of the European Synchrotron Radiation Facilities (ESRF) in Grenoble⁴³ on powdered samples (ca. 15 mg) diluted with B₄C and embedded in paraffin wax. The incident energy was selected using the <311> reflection of a double Si crystal monochromator. Rejection of higher harmonics was achieved by three Si mirrors at an angle of 2.5 mrad relative to the incident beam. The beam size was estimated to be ~ 0.3 mm vertically and 1 mm horizontally. X-Ray absorption near-edge structure (XANES) spectra were measured in high energy resolution fluorescence detection (HERFD) mode using an X-ray emission spectrometer.44 The sample, analyzer crystal and photon detector (avalanche photodiode) were arranged in a vertical Rowland geometry. The Yb HERFD spectra at the $L_{\rm III}$ edge were obtained by recording the maximum intensity of the Yb $L\alpha_1$ emission line (7416 eV) as a function of the incident energy. The emission

energy was selected using the $\langle 620 \rangle$ reflection of five spherically-bent Ge-crystal analyzers (with 1 m bending radius) aligned at 69° Bragg angle. The full core-to-valence resonant inelastic X-ray scattering (RIXS) plane around the Yb L_{III} edge was measured by scanning the incident energy at different emission energies. The emission energy in that case was selected using the $\langle 800 \rangle$ reflection of two spherically-bent Ge-crystal analyzers aligned at 79° Bragg angle for the measurements of the Yb₃Pt₄Ge₁₃ sample and one crystal analyzer for the measurements of the Yb₂O₃ sample. The intensity was normalized to the incident flux. A combined (incident convoluted with emitted) energy resolution of 1.2 and 1.4 eV was achieved in the HERFD and core-to-valence RIXS measurements, respectively.

Acknowledgements

We are indebted to Yu. Prots for performing high-resolution X-ray diffraction measurements and helpful discussions. We thank P. Scheppan and S. Kostmann for metallographic and EDXS studies of the sample. The help of S. Leipe with high-pressure syntheses is gratefully acknowledged. A.T. was funded by Alexander von Humbolt Foundation.

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